



Model: ZX10

Max. power 100 mW	IP 50	Diode laser	Boresight error < 0.8 mrad	Fixed focus	Easy installation	3.5 - 5.5 VDC	Power con- sumption < 1.5 W
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Small size, high performance

The ZX-laser series offers diverse, application specific customization possibilities. The user can choose from IR and red wavelengths depending on the application and material to be inspected.

The ZX-laser reaches an unrivalled accuracy with its boresight error of less than 0.8 mrad.

The industrial-suited design along with stable performance works perfectly as an integrated module in machine vision applications, sensors or processing machines.

HIGHLIGHTS

- Repeatable high product quality due to automated production processes
- Highest reproducibility of beam quality
- Optical output power up to 100 mW
- Wavelengths from 635 nm 830 nm
- Fixed focus
- IP 50 (optional IP 67)

APPLICATIONS

- · Positioning tasks
- Machine Vision
- Triangulation sensors
- 3D-Measurement
- Metrology

	ORDER CODE									
Z ??	-	X10	-	?	-	?	-	?	-	?
Power		Product name		Electronics		F = focusable		Wavelength		Optics



SYSTEMSPEZIFIKATIONEN

Wavelength	nm
Wavelength tolerance	nm (typical)
Wavelength drift	nm / K (typical)
Output power	mW
Spatial mode	(typical)
RMS noise	(20 Hz to 20 MHz, typical)
Peak-to-Peak Noise	(20 Hz to 20 MHz, typical)
Boresight error ⁽¹⁾	mrad (typical)
Line orientation ⁽²⁾	mrad
Pointing stability	µrad / K
Long-term power stability	(24 h)
Start-up time	μs
Laser operation mode	

635-685 nm	785-830 nm			
±10 nm	±4 nm			
< 0,25 nm	< 0,25 nm			
≤ 100 mW	≤ 100 mW			
Single transverse mode				
< 0.5 %				
< 1 %				
< 0.8 mrad				
< 10 mrad				
< 10 µrad / K				
±3 % over the entire temperature range				
< 70 μs				
APC				

ELECTRICAL SPECIFICATION⁽³⁾

Operating voltage	VDC				
Operating current	(max. at 25 °C)				
Protection					
Electrical isolation					
Connection					
Power consumption					

3.5 - 5.5 VDC			
< 250 mA			
LED status indicator, reverse polarity protection, ESD			
Potential-free housing			
Texas plug			
< 1.5 W			

OPTICAL SPECIFICATION

Fan angles (4)	Degrees		
Line straightness ⁽⁵⁾	% (of line length)		
Line uniformity ⁽⁶⁾	% (typical)		
Dot			
DOE			
Focus range	mm		

5°, 10°, 20°, 30°, 45°, 60°, 75°, 90° (homogeneous line) 3°, 5°, 10°, 15°, 20°, 30°, 90° (Gaussian line profile)			
< 0.05 %			
< 25 %			
Point elliptical			
Multi line, crosses, grids, etc.			
100 mm up to 10,000 mm (only available as fixed focus)			

FUSSNOTEN

⁽¹⁾ Boresight error	Also known as pitch and skew
⁽²⁾ Line orientation	Also known as line tilt (roll), with reference to the indentation in the clamping area
⁽³⁾ In combination with M-electronic (M=mini).	Also available as ND-version (no driver) without driver electronics for OEM applications.
⁽⁴⁾ Line length / fan angle	at > 13.5 % I _{max}
⁽⁵⁾ Line straightness	Deviation from best fit line over the middle 80% of the line, for homogeneous lines
⁽⁶⁾ Line uniformity	Maximum relative optical power variation over the middle 80% of the line, for homogeneous lines and fixed focus



LINE THICKNESS VS. WORKING DISTANCE*



DOF VS. WORKING DISTANCE*



Wavelength		Calculati for line	ion factor e width	Calculation factor for depth of focus		
		slp**	elp**	slp**	elp**	
Red	640 nm	1.28	1.00	0.70	0.95	
Red	660 nm	1.00	1.00	1.00	1.00	
IR	830 nm	1.30	2.11	1.03	2.20	

Optical configurations for several line settings are available.

- slp** = standard line Powell; standard setup with medium line thickness and depth of focus.

- elp** = extended line Powell; lines with advanced depth of focus and thicker lines. Recommended for fan angles > 75° at working distances < 500 mm.

The graphs above show the values for line width and depth of focus of a 660 nm laser. To get the values for a different wavelength the factor from the table above has to be multiplied by the values from the graphs.

Example: 660 nm laser focused at 1 m working distance:

line width approx. 200 μm (@ slp** optic); Depth of focus approx. 350 mm (values from the graphs) Calculated: 830 nm laser focused at 1 m working distance:

line width approx. 200 μ m x 1.30 = 260 μ m; Depth of focus approx. 350 mm x 1.03 = 360,5 mm

* Values in the graphs for homogenous line profiles.

** Fan angle: 5° - 90°

ENVIRONMENTAL CONDITIONS

Operating temperature	°C / °F		
Storage temperature	°C / °F		
Humidity	%		
Dissipated heat	W		
Shock and vibration			

-10 °C to +50 °C / 14 °F to +122 °F	
-40 °C to +85 °C / -40 °F to +185 °F	
< 90 %, non-condensing	
< 1 W	
According to IEC EN 61373:2011, cat. 2	

MECHANICAL SPECIFICATIONS

		ZX10-M	ZX10-ND (OEM)	
Weight	g / Ibs	8 g / 0.02 lbs	5 g / 0.01 lbs	
Length	mm / inch	33 mm / 1.30 in	22.5 mm / 0.89 in	
Diameter head ø	mm / inch	10h7 mm / 0.39 in		
Length of cable	mm / inch	2,000 mm / 78.74 in		
Connection		2 flying leads (optional Texas plug)		
Material		Stainless steel		
Protection class		IP 50 (IP 67 optional)	IP 50 (IP 67 optional)	







VARIATION

For OEM-applications (e.g. sensor heads) the ZX10 is also available as a ZX10-ND (no driver) version.



